

SD103AWS-SD103CWS SURFACE MOUNT SCHOTTKY BARRIER RECTIFIER DIODE



Features

- Low Turn-on Voltage
- Fast Switching
- PN Junction Guard Ring Transient and ESD Protection
- Designed for Surface Mount Application
- Plastic Material —UL Recognition Flammability Classification 94V-0
- Green Products in Compliance with the ROHS Directive
- This is a Pb – Free Device
- All SMC parts are traceable to the wafer lot
- Additional testina can be offered upon request

Schematic & Pin Configuration



Mechanical Characteristics

- Case: SOD-323, Molded plastic
- Terminals: Plated Leads Solderable per MIL-STD-202, Method 208
- Polarity: Cathode Band
- Weight: 0.04 grams(approx)

Maximum Ratings @ $T_A=25^{\circ}\text{C}$ unless otherwise specified

Single Phase, half wave, 60Hz, resistive or inductive load. For capacitive load, derate current by 20%.

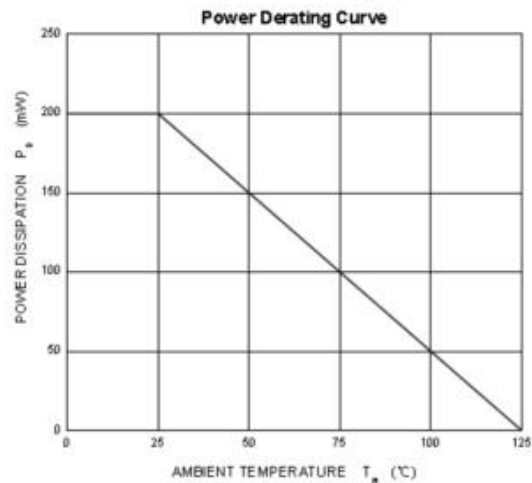
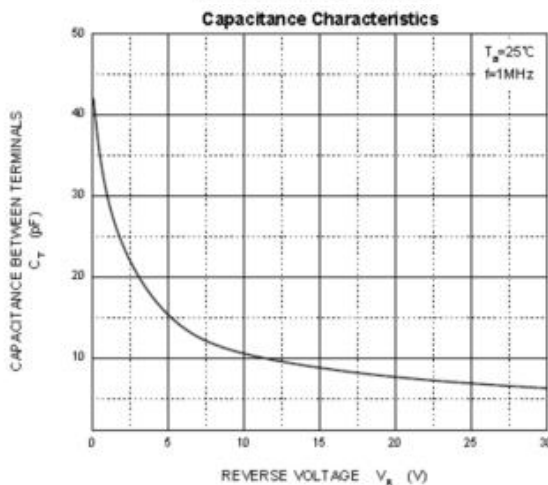
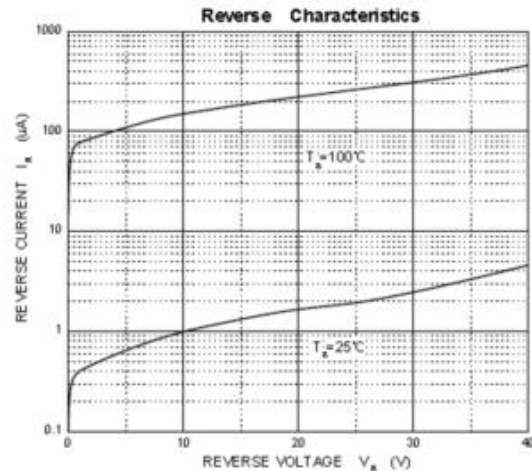
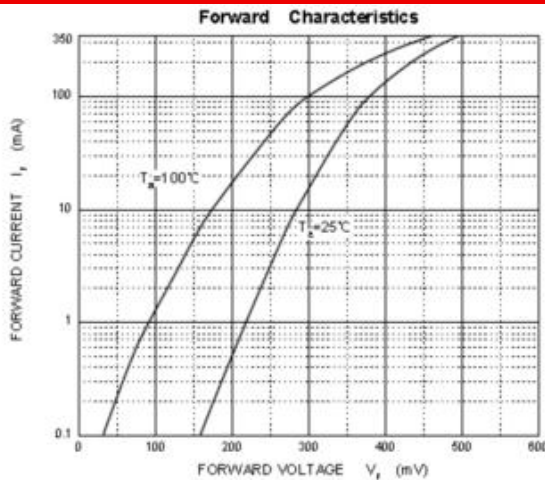
Characteristic	Symbol	SD103AWS	SD103BWS	SD103CWS	Units
Peak Repetitive Reverse Voltage	V_{RRM}	40	30	20	V
Working Peak Reverse Voltage	V_{RWM}				
DC Blocking Voltage	V_R				
RMS Reverse Voltage	$V_{R(RMS)}$	28	21	14	V
Forward Continuous Current	I_{FM}	0.35			A
Non-Repetitive Peak Forward Surge Current 8.3ms Single half sine-wave superimposed on rated load (JEDEC Method)	I_{FSM}	2			A
Power Dissipation	P_d	200			mW
Typical Thermal Resistance Junction to Ambient	$R_{\theta JA}$	500			$^{\circ}\text{C/W}$
Junction Temperature Range	T_J	125			$^{\circ}\text{C}$
Storage Temperature Range	T_{STG}	-55 to +150			$^{\circ}\text{C}$

Electrical Characteristics @ $T_A=25^\circ\text{C}$ unless otherwise specified

Characteristic	Symbol	Min	Typ	Max	Units	Test Condition
Reverse Breakdown Voltage *	$V_{(BR)}$	40	-	-	V	$I_R=100\mu\text{A}$ SD103AWS
		30				$I_R=100\mu\text{A}$ SD103BWS
		20				$I_R=100\mu\text{A}$ SD103CWS
Forward Voltage *	V_{FM}	-	-	0.37	V	$I_F=20\text{mA}$
		-	-	0.60	V	$I_F=200\text{mA}$
Reverse Leakage Current *	I_{RM}	-	-	5	μA	$V_R=30\text{V}$ SD103AWS
		-	-			$V_R=20\text{V}$ SD103BWS
		-	-			$V_R=10\text{V}$ SD103CWS
Capacitance between terminals	C_T	-	-	50	pF	$V_R=0\text{V}, f=1.0\text{MHz}$
Reverse recovery time	t_{rr}	-	10	-	ns	$I_F=I_R=200\text{mA}, I_{rr}=0.1 \times I_R, R_L=100\Omega$

* Pulse width < 300 μs , duty cycle < 2%

Ratings and Characteristics Curves



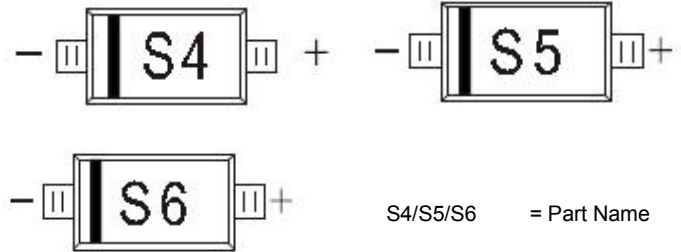
- China - Germany - Korea - Singapore - United States •
- <http://www.smc-diodes.com> - sales@smc-diodes.com •

Ordering Information

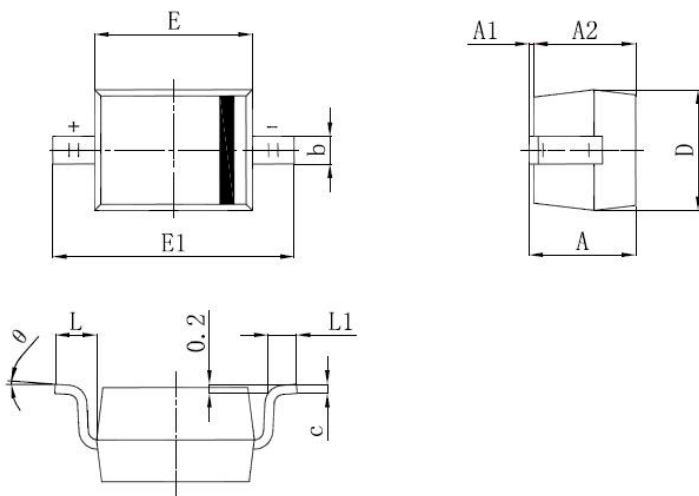
Device	Package	Shipping
SD103AWS-SD103CWS	SOD-323 (Pb-Free)	3000pcs / reel

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging specification.

Marking Diagram

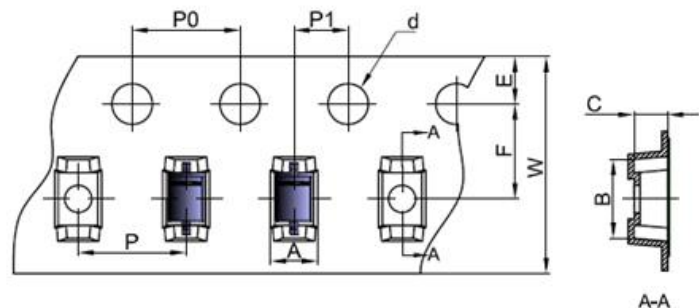


Mechanical Dimensions SOD-323



SYMBOL	Millimeters		Inches	
	MIN.	MAX.	MIN.	MAX.
A	-	1.000	-	0.039
A1	0.000	0.100	0.000	0.004
A2	0.800	0.900	0.031	0.035
b	0.250	0.350	0.010	0.014
c	0.080	0.150	0.003	0.006
D	1.200	1.400	0.047	0.055
E	1.600	1.800	0.063	0.071
E1	2.500	2.700	0.098	0.106
L	0.475 REF.		0.019 REF.	
L1	0.250	0.400	0.010	0.016
θ	0°	8°	0°	8°

Carrier Tape Specification SOD-323



SYMB OL	Millimeters	
	Min.	Max.
B	2.85	2.95
C	1.20	1.30
d	1.40	1.60
E	1.65	1.85
F	3.40	3.60
P	3.90	4.10
P0	3.90	4.10
P1	1.90	2.10
W	7.90	8.30



DISCLAIMER:

- 1- The information given herein, including the specifications and dimensions, is subject to change without prior notice to improve product characteristics. Before ordering, purchasers are advised to contact the SMC Diode Solutions sales department for the latest version of the datasheet(s).
- 2- In cases where extremely high reliability is required (such as use in nuclear power control, aerospace and aviation, traffic equipment, medical equipment, and safety equipment), safety should be ensured by using semiconductor devices that feature assured safety or by means of users' fail-safe precautions or other arrangement.
- 3- In no event shall SMC Diode Solutions be liable for any damages that may result from an accident or any other cause during operation of the user's units according to the datasheet(s). SMC Diode Solution assumes no responsibility for any intellectual property claims or any other problems that may result from applications of information, products or circuits described in the datasheets.
- 4- In no event shall SMC Diode Solutions be liable for any failure in a semiconductor device or any secondary damage resulting from use at a value exceeding the absolute maximum rating.
- 5- No license is granted by the datasheet(s) under any patents or other rights of any third party or SMC Diode Solutions.
- 6- The datasheet(s) may not be reproduced or duplicated, in any form, in whole or part, without the expressed written permission of SMC Diode Solutions.
- 7- The products (technologies) described in the datasheet(s) are not to be provided to any party whose purpose in their application will hinder maintenance of international peace and safety nor are they to be applied to that purpose by their direct purchasers or any third party. When exporting these products (technologies), the necessary procedures are to be taken in accordance with related laws and regulations..